## DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

DOCKET NO. **TS01-714** 

As a below named Inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

A Method of Forming a Stacked Capacitor Structure With Increased Surface Area For A DRAM Device

the specification of which (check one)		
X is attached hereto.		
was filed on		
Application Serial No.		
and was amended on		
I hereby state that I have reviewed and und amended by any amendment referred to ab	leisiann ine contents of the s	bove Identified specification including the claims, as
I acknowledge the duty to disclose informa 37, Code of Federal Regulations, §1.56(a).	ntion which is material to the	examination of this application in accordance with Title
I hereby claim foreign priority benefits und inventor's certificate listed below and have a filing date before that of the application of the prior Foreign Application(s)	er Title 35, United States Co also identified below any for on which priority is claimed:	ode §119 of any foreign application(s) for patent or reign application for patent or inventor's certificate having
		Priority Claimed:
(Number)	(Country)	(Day/Month/Year Filed)
(Number)	(Country)	(Day/Month/Year Filed)
1 hereby claim the benefit under Title 35, Usas the subject matter of each of the claims of provided by the first paragraph of Title 35, defined in Title 37, Code of Federal Regula national or PCT international filing date of	nited States Code §120 of a of this application is not disci United States Code, §112, I ations, §1.56(a) which occurre this application:	ny United States application(s) listed below and, insofar losed in the prior United States application in the manner acknowledge the duty to disclose material information as red between the filing date of the prior application and the
(Application Serial No.) (F	Filing Date) (Status)	(patented, pending, abandoned)
I hereby declare that all statements made he belief are believed to be true; and further th the like so made are punishable by fine or in that such willful false statements may jeopa	erein of my own knowledge a lat these statements were ma apprisonment, or both, under rdize the validity of the appli	de with the knowledge that willful false statements and Section 1001 of Title 18 of the United States Code and cation or any patent issued thereon.
POWER OF ATTORNEY: As a named invapplication and transact all business in the F	rentor, I hereby appoint the for a ratent and Trademark Office	ollowing attorney(s) and/or agent(s) to prosecute this connected therewith. (list name & registration no.)
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